B-Suffix Series CMOS Gates

MC14001B, MC14011B, MC14023B, MC14025B, MC14071B, MC14073B, MC14081B, MC14082B

The B Series logic gates are constructed with P and N channel enhancement mode devices in a single monolithic structure (Complementary MOS). Their primary use is where low power dissipation and/or high noise immunity is desired.

Features

- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- All Outputs Buffered
- Capable of Driving Two Low-power TTL Loads or One Low-power Schottky TTL Load Over the Rated Temperature Range.
- Double Diode Protection on All Inputs Except: Triple Diode Protection on MC14011B and MC14081B
- Pin-for-Pin Replacements for Corresponding CD4000 Series B Suffix Devices
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (Voltages Referenced to VSS)

Symbol	Parameter	Value	Unit
V_{DD}	DC Supply Voltage Range	-0.5 to +18.0	V
V _{in} , V _{out}	Input or Output Voltage Range (DC or Transient)	ge Range -0.5 to V _{DD} + 0.5	
I _{in} , I _{out}	Input or Output Current (DC or Transient) per Pin	±10	mA
P _D	Power Dissipation, per Package (Note 1)	per Package 500	
T _A	Ambient Temperature Range	-55 to +125	°C
T _{stg}	Storage Temperature Range	-65 to +150	°C
TL	Lead Temperature (8–Second Soldering)	260	°C
V _{ESD}	ESD Withstand Voltage Human Body Model Machine Model Charged Device Model	> 3000 > 300 N/A	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Temperature Derating: "D/DW" Packages: -7.0 mW/°C From 65°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}.$

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.



ON Semiconductor®

http://onsemi.com





SOIC-14 D SUFFIX CASE 751A TSSOP-14 DT SUFFIX CASE 948G

MARKING DIAGRAMS





SOIC-14

TSSOP-14

xx = Specific Device Code A = Assembly Location

WL, L = Wafer Lot YY, Y = Year WW, W = Work Week G or ■ = Pb-Free Package

(Note: Microdot may be in either location)

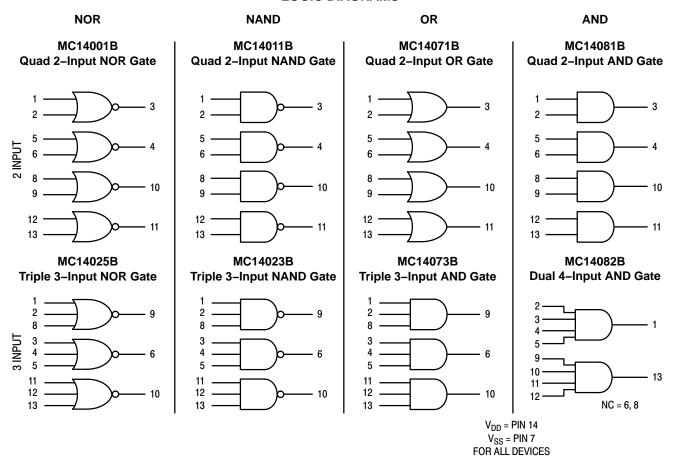
DEVICE INFORMATION

Device	Description
MC14001B	Quad 2-Input NOR Gate
MC14011B	Quad 2-Input NAND Gate
MC14023B	Triple 3-Input NAND Gate
MC14025B	Triple 3-Input NOR Gate
MC14071B	Quad 2-Input OR Gate
MC14073B	Triple 3-Input AND Gate
MC14081B	Quad 2-Input AND Gate
MC14082B	Dual 4-Input AND Gate

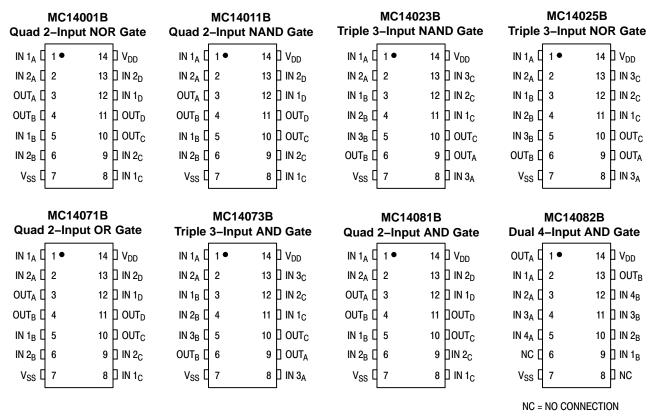
ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

LOGIC DIAGRAMS



PIN ASSIGNMENTS



ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

				- 5	5°C		25°C		125	5°C	
Characteristic		Symbol	V _{DD} Vdc	Min	Max	Min	Typ (Note 2)	Max	Min	Max	Unit
Output Voltage V _{in} = V _{DD} or 0	"0" Level	V _{OL}	5.0 10 15	- - -	0.05 0.05 0.05	- - -	0 0 0	0.05 0.05 0.05	- - -	0.05 0.05 0.05	Vdc
$V_{in} = 0$ or V_{DD}	"1" Level	V _{OH}	5.0 10 15	4.95 9.95 14.95		4.95 9.95 14.95	5.0 10 15		4.95 9.95 14.95	- - -	Vdc
Input Voltage $(V_O = 4.5 \text{ or } 0.5 \text{ Vdc})$ $(V_O = 9.0 \text{ or } 1.0 \text{ Vdc})$ $(V_O = 13.5 \text{ or } 1.5 \text{ Vdc})$	"0" Level	V _{IL}	5.0 10 15	- - -	1.5 3.0 4.0	_ _ _	2.25 4.50 6.75	1.5 3.0 4.0	- - -	1.5 3.0 4.0	Vdc
$(V_O = 0.5 \text{ or } 4.5 \text{ Vdc})$ $(V_O = 1.0 \text{ or } 9.0 \text{ Vdc})$ $(V_O = 1.5 \text{ or } 13.5 \text{ Vdc})$	"1" Level	V _{IH}	5.0 10 15	3.5 7.0 11	- - -	3.5 7.0 11	2.75 5.50 8.25	- - -	3.5 7.0 11	- - -	Vdc
Output Drive Current $(V_{OH} = 2.5 \text{ Vdc})$ $(V_{OH} = 4.6 \text{ Vdc})$ $(V_{OH} = 9.5 \text{ Vdc})$ $(V_{OH} = 13.5 \text{ Vdc})$	Source	I _{OH}	5.0 5.0 10 15	-3.0 -0.64 -1.6 -4.2	- - -	-2.4 -0.51 -1.3 -3.4	-4.2 -0.88 -2.25 -8.8	- - -	-1.7 -0.36 -0.9 -2.4	- - -	mAdc
$(V_{OL} = 0.4 \text{ Vdc})$ $(V_{OL} = 0.5 \text{ Vdc})$ $(V_{OL} = 1.5 \text{ Vdc})$	Sink	I _{OL}	5.0 10 15	0.64 1.6 4.2	- - -	0.51 1.3 3.4	0.88 2.25 8.8	- - -	0.36 0.9 2.4	- - -	mAdc
Input Current		l _{in}	15	_	±0.1	_	±0.00001	±0.1	_	±1.0	μAdc
Input Capacitance (V _{in} = 0)		C _{in}	-	-	-	-	5.0	7.5	-	-	pF
Quiescent Current (Per Package)		I _{DD}	5.0 10 15	- - -	0.25 0.5 1.0	- - -	0.0005 0.0010 0.0015	0.25 0.5 1.0	- - -	7.5 15 30	μAdc
Total Supply Current (Note (Dynamic plus Quiesce Per Gate, C _L = 50 pF)		I _T	5.0 10 15			$I_{T} = (0.$	3 μA/kHz) f - 6 μA/kHz) f - 9 μA/kHz) f -	+ I _{DD} /N	•		μAdc

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.
 The formulas given are for the typical characteristics only at 25°C.
- 4. To calculate total supply current at loads other than 50 pF:

$$I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) \text{ Vfk}$$

where: I_T is in μA (per package), C_L in pF, $V = (V_{DD} - V_{SS})$ in volts, f in kHz is input frequency, and k = 0.001 x the number of exercised gates per package.

B-SERIES GATE SWITCHING TIMES

SWITCHING CHARACTERISTICS (Note 5) ($C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C}$)

Characteristic	Symbol	V _{DD} Vdc	Min	Typ (Note 6)	Max	Unit
Output Rise Time, All B-Series Gates	t _{TLH}					ns
$t_{TLH} = (1.35 \text{ ns/pF}) C_L + 33 \text{ ns}$		5.0	_	100	200	
$t_{TLH} = (0.60 \text{ ns/pF}) C_L + 20 \text{ ns}$		10	_	50	100	
$t_{TLH} = (0.40 \text{ ns/PF}) C_L + 20 \text{ ns}$		15	_	40	80	
Output Fall Time, All B-Series Gates	t _{THL}					ns
$t_{THL} = (1.35 \text{ ns/pF}) C_L + 33 \text{ ns}$		5.0	_	100	200	
$t_{THL} = (0.60 \text{ ns/pF}) C_L + 20 \text{ ns}$		10	_	50	100	
$t_{THL} = (0.40 \text{ ns/pF}) C_L + 20 \text{ ns}$		15	_	40	80	
Propagation Delay Time	t _{PLH} , t _{PHL}					ns
MC14001B, MC14011B only						
t_{PLH} , $t_{PHL} = (0.90 \text{ ns/pF}) C_L + 80 \text{ ns}$		5.0	_	125	250	
t_{PLH} , $t_{PHL} = (0.36 \text{ ns/pF}) C_L + 32 \text{ ns}$		10	_	50	100	
t_{PLH} , $t_{PHL} = (0.26 \text{ ns/pF}) C_L + 27 \text{ ns}$		15	_	40	80	
All Other 2, 3, and 4 Input Gates						
t_{PLH} , $t_{PHL} = (0.90 \text{ ns/pF}) C_L + 115 \text{ ns}$		5.0	_	160	300	
t_{PLH} , $t_{PHL} = (0.36 \text{ ns/pF}) C_L + 47 \text{ ns}$		10	_	65	130	
t_{PLH} , $t_{PHL} = (0.26 \text{ ns/pF}) C_L + 37 \text{ ns}$		15	_	50	100	
8-Input Gates (MC14068B, MC14078B)						
t_{PLH} , $t_{PHL} = (0.90 \text{ ns/pF}) C_L + 155 \text{ ns}$		5.0	_	200	350	
t_{PLH} , $t_{PHL} = (0.36 \text{ ns/pF}) C_L + 62 \text{ ns}$		10	_	80	150	
t_{PLH} , $t_{PHL} = (0.26 \text{ ns/pF}) C_L + 47 \text{ ns}$		15	_	60	110	

^{5.} The formulas given are for the typical characteristics only at 25°C.

^{6.} Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

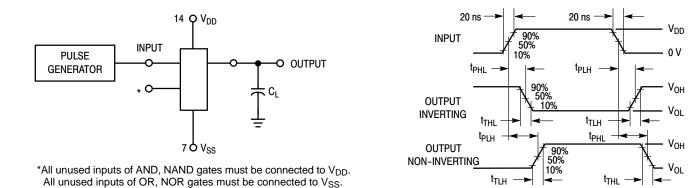
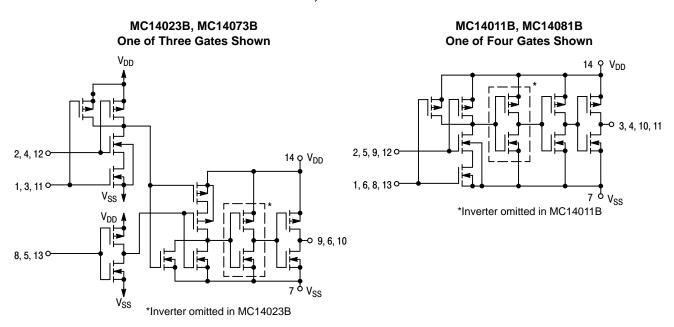


Figure 1. Switching Time Test Circuit and Waveforms

CIRCUIT SCHEMATIC NOR, OR GATES

MC14001B, MC14071B MC14025B One of Four Gates Shown One of Three Gates Shown 14 9 V_{DD} 1, 3, 11 0 1, 6, 8, 13 o-2, 4, 12 0 2, 5, 9, 12 0-14 9 V_{DD} 0 3, 4, 10, 11 V_{SS} 0 9, 6, 10 V_{SS} V_{DD} ♠ *Inverter omitted in MC14001B 8, 5, 13 0 *Inverter omitted in MC14025B

CIRCUIT SCHEMATIC NAND, AND GATES



TYPICAL B-SERIES GATE CHARACTERISTICS

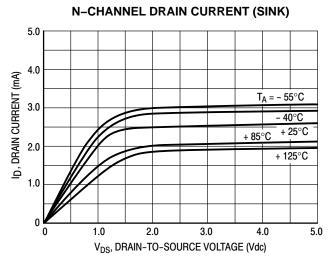


Figure 2. $V_{GS} = 5.0 \text{ Vdc}$

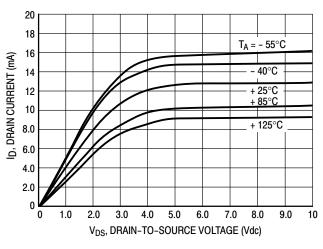


Figure 4. V_{GS} = 10 Vdc

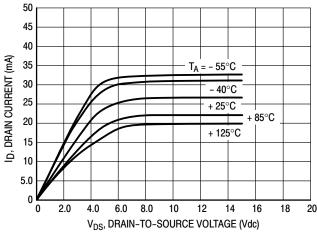


Figure 6. V_{GS} = 15 Vdc

P-CHANNEL DRAIN CURRENT (SOURCE) - 10 - 9.0 - 8.0 $T_A = -55^{\circ}C$ ID, DRAIN CURRENT (mA) - 7.0 - 6.0 - 5.0 + 25°C - 85°C - 4.0 125°C - 3.0 - 2.0 - 1.0 - 1.0 - 2.0 - 3.0 - 4.0 - 5.0 V_{DS}, DRAIN-TO-SOURCE VOLTAGE (Vdc)

Figure 3. $V_{GS} = -5.0 \text{ Vdc}$

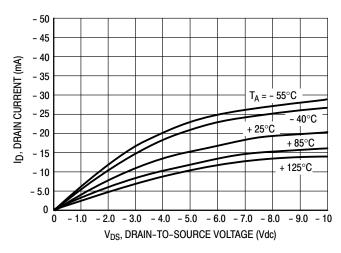


Figure 5. $V_{GS} = -10 \text{ Vdc}$

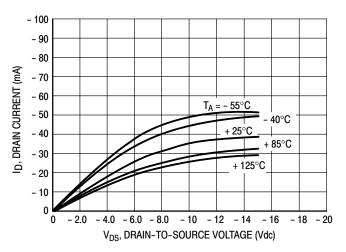


Figure 7. $V_{GS} = -15 \text{ Vdc}$

These typical curves are not guarantees, but are design aids. Caution: The maximum rating for output current is 10 mA per pin.

TYPICAL B-SERIES GATE CHARACTERISTICS (cont'd)

VOLTAGE TRANSFER CHARACTERISTICS

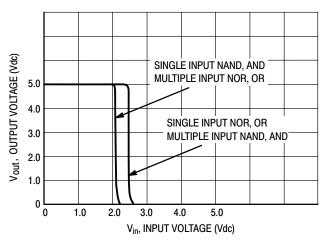


Figure 8. $V_{DD} = 5.0 \text{ Vdc}$

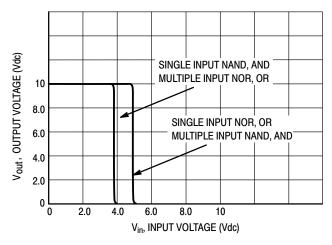


Figure 9. V_{DD} = 10 Vdc

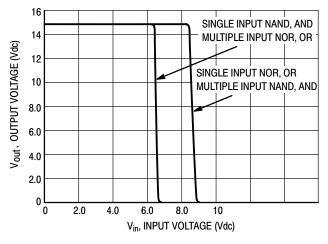


Figure 10. $V_{DD} = 15 \text{ Vdc}$

DC NOISE MARGIN

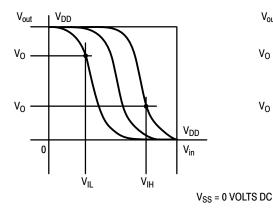
The DC noise margin is defined as the input voltage range from an ideal "1" or "0" input level which does not produce output state change(s). The typical and guaranteed limit values of the input values V_{IL} and V_{IH} for the output(s) to be at a fixed voltage V_O are given in the Electrical Characteristics table. V_{IL} and V_{IH} are presented graphically in Figure 11.

Guaranteed minimum noise margins for both the "1" and "0" levels =

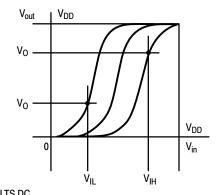
1.0 V with a 5.0 V supply

2.0 V with a 10.0 V supply

2.5 V with a 15.0 V supply



(a) Inverting Function



(b) Non-Inverting Function

Figure 11. DC Noise Immunity

ORDERING INFORMATION

Device	Package	Shipping [†]
MC14001BDG	SOIC-14	55 H-2- / D-2
NLV14001BDG*	(Pb-Free)	55 Units / Rail
MC14001BDR2G	SOIC-14	
NLV14001BDR2G*	(Pb-Free)	OFFICE Living / Towns O. Doorl
MC14001BDTR2G	TSSOP-14	2500 Units / Tape & Reel
NLV14001BDTR2G*	(Pb-Free)	
MC14001BFELG	SOEIAJ-14	2000 Units / Tape & Reel
	(Pb-Free)	
MC14011BDG	SOIC-14	
NLV14011BDG*	(Pb–Free)	55 Units / Rail
MC14011BDR2G	SOIC-14	
NLV14011BDR2G*	(Pb–Free)	
MC14011BDTR2G	TSSOP-14	2500 Units / Tape & Reel
NLV14011BDTR2G*	(Pb-Free)	
MC14011BFG	SOEIAJ-14	50 Units / Rail
MC14011BFELG	(Pb-Free)	2000 Units / Tape & Reel
MC14023BDG	SOIC-14 (Pb-Free)	55 Units / Rail
MC14023BDR2G	SOIC-14	2500 Unite / Tana & Book
NLV14023BDR2G*	(Pb-Free)	2500 Units / Tape & Reel
MC14023BFELG	SOEIAJ-14 (Pb-Free)	2000 Units / Tape & Reel
MC14025BDG	2010.44	
NLV14025BDG*	SOIC-14 (Pb-Free)	55 Units / Rail
MC14025BDR2G	0010 44	
NLV14025BDR2G*	SOIC-14 (Pb-Free)	2500 Units / Tape & Reel
	<u> </u>	
MC14071BDG	SOIC-14	EE Unite / Boil
NLV14071BDG*	(Pb-Free)	55 Units / Rail
MC14071BDR2G	SOIC-14	2500 Unite / Tana 9 Deal
NLV14071BDR2G*	(Pb-Free)	2500 Units / Tape & Reel
MC14071BDTG		96 Units per Rail
MC14071BDTR2G	TSSOP-14 (Pb-Free)	2500 Unite / Tana 9 Deal
NLV14071BDTR2G*		2500 Units / Tape & Reel
MC14073BDG	SOIC-14	FE 11-2- / P-2
	(Pb-Free)	55 Units / Rail
MC14073BDR2G	SOIC-14 (Pb-Free)	2500 Units / Tape & Reel

ORDERING INFORMATION (continued)

Device	Package	Shipping [†]	
MC14081BDG	SOIC-14	5511-75 / P-7	
NLV14081BDG*	(Pb-Free)	55 Units / Rail	
MC14081BDR2G	SOIC-14		
NLV14081BDR2G*	(Pb-Free)	0500 H % /T 0 D 1	
MC14081BDTR2G	TSSOP-14	2500 Units / Tape & Reel	
NLV14081BDTR2G*	(Pb-Free)		

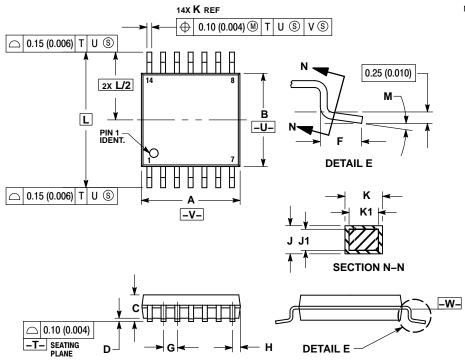
MC14082BDG		EE Unito / Doil
NLV14082BDG*	SOIC-14 (Pb-Free)	55 Units / Rail
MC14082BDR2G	,	2500 Units / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable.

PACKAGE DIMENSIONS

TSSOP-14 CASE 948G **ISSUE B**



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
 - ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION A DOES NOT INCLUDE MOLD
 FLASH, PROTRUSIONS OR GATE BURRS.
 - FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

 5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K
 - (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.

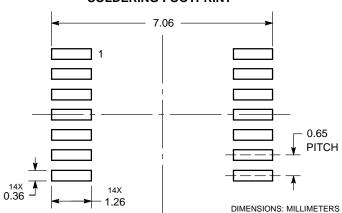
 6. TERMINAL NUMBERS ARE SHOWN FOR

 - REFERENCE ONLY.

 7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE –W–.

	MILLIN	IETERS	INCHES	
DIM	MIN	MAX	MIN	MAX
Α	4.90	5.10	0.193	0.200
В	4.30	4.50	0.169	0.177
С		1.20		0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65	BSC	0.026 BSC	
Н	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
Г	6.40 BSC		0.252 BSC	
М	0 °	8 °	0 °	8 °

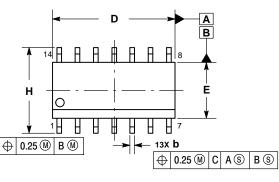
SOLDERING FOOTPRINT*

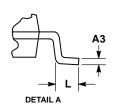


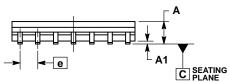
*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

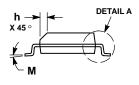
PACKAGE DIMENSIONS

SOIC-14 NB CASE 751A-03 ISSUE K









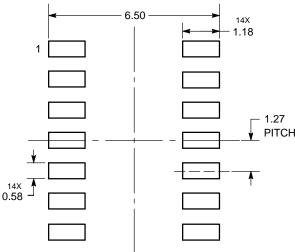
NOTES

- 1. DIMENSIONING AND TOLERANCING PER
- DIMENSIONING AND TOLERANGING FER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT
- MAXIMUM MATERIAL CONDITION.
 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.

 5. MAXIMUM MOLD PROTRUSION 0.15 PER

	MILLIN	IETERS	INCHES	
DIM	MIN	MAX	MIN	MAX
Α	1.35	1.75	0.054	0.068
A1	0.10	0.25	0.004	0.010
A3	0.19	0.25	0.008	0.010
b	0.35	0.49	0.014	0.019
D	8.55	8.75	0.337	0.344
Е	3.80	4.00	0.150	0.157
е	1.27	BSC	0.050	BSC
Н	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.019
٦	0.40	1.25	0.016	0.049
М	0°	7°	0 °	7°

SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and the 👊 are registered trademarks of Semiconductor Components Industries, LLC (SCILLC) or its subsidiaries in the United States and/or other countries. SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent–Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights of others. SCILLC products are not designed, intended, a customer application in which the product of the respective products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA

Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada **Fax**: 303–675–2176 or 800–344–3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81–3–5817–1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor:

 MC14001BCPG
 MC14001BD
 MC14001BDRG
 MC14001BDR2G
 MC14001BDTR2
 MC14001BDTR2G

 MC14001BFEL
 MC14001BFELG
 MC14011BCPG
 MC14011BD
 MC14011BDG
 MC14011BDR2G
 MC14011BDR2G
 MC14011BDR2G
 MC14011BDR2G
 MC14011BDR2G
 MC14011BDR2G
 MC14023BCPG

 MC14023BD
 MC14023BDG
 MC14023BDR2G
 MC14023BFEL
 MC14023BFELG
 MC14025BCP
 MC14025BCPG

 MC14025BD
 MC14025BDG
 MC14025BDR2G
 MC14025BFEL
 MC14071BCP
 MC14071BCPG
 MC14071BD

 MC14071BDG
 MC14071BDR2G
 MC14071BDT
 MC14071BDTG
 MC14071BDTR2
 MC14071BDTR2

 MC14071BDTR2G
 MC14071BFEL
 MC14073BCP
 MC14073BCPG
 MC14073BD
 MC14073BDG

 MC14073BDR2
 MC14073BDR2G
 MC14073BFEL
 MC14073BFELG
 MC14081BCP
 MC14081BCP
 MC14081BCP
 MC14081BCP
 MC14081BDCP
 MC14081BDCP
 MC14081BDCP
 MC14081BDCP
 MC14081BDCP
 MC14082BCP
 MC14082BCP
 MC14082BDR2G
 NLV14081BDTR2G
 NLV14081BDTR2G
 NLV14081BDTR2G
 NLV14001BDG
 NLV14071BDG
 NLV14071BDG